TOSHIBA Photocoupler IRED + Photo IC

# TLP705F

Plasma Display Panel Industrial Inverter IGBT/Power MOS FET Gate Drive

TLP705F consists of an infrared LED and an integrated photodetector. This unit is 6-lead SDIP package. TLP705F is 50% smaller than 8pin DIP and has suited the safety standard reinforced insulation class. So mounting area in safety standard required equipment can be reduced. TLP705F is suitable for gate driving circuit of IGBT or power MOS FET. Especially TLP705F is capable of "direct" gate drive of lower Power IGBTs.

Peak output current : ±0.45 A (max)
 Operating frequency : 250kHz (max)
 Guaranteed performance over temperature : -40 to 100°C

Supply current : 3.0mA (max)
 Power supply voltage : 10 to 20 V

Threshold input current : IFLH = 8 mA (max)

Switching time (tpLH / tpHL) : 200 ns (max)
 Common mode transient immunity : 10 kV/µs (min)

Isolation voltage : 5000 Vrms (min)

· Construction Mechanical Rating

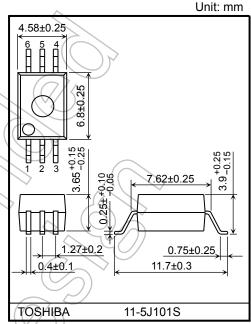
| 8.0 mm (min) |
|--------------|
| 8.0 mm (min) |
| 0.4 mm (min) |
|              |

- UL-recognized: UL 1577, File No.E67349
- cUL-recognized : CSA Component Acceptance Service No.5A
   File No.E67349
- VDE-approved : EN 60747-5-5 , EN 62368-1 (Note 1)

Note 1: When a VDE approved type is needed, please designate the **Option(D4)**.

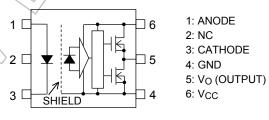
#### **Truth Table**

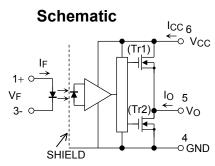
|       |     |     |     | 1           |
|-------|-----|-----|-----|-------------|
| Input | LED | Try | Tr2 | /<br>Output |
| Н     | ON  | ON  | OFF | Н           |
| L     | OFF | OFF | ON  | L           |



Weight: 0.26 g (typ.)

## Pin Configuration (Top View)





Note: A 0.1  $\mu F$  bypass capacitor must be connected between pins 6 and 4.

Start of commercial production 2004-04

### **Absolute Maximum Ratings (Ta = 25°C)**

|  | Characteristics                      |                  | Symbol               | Rating     | Unit    |
|--|--------------------------------------|------------------|----------------------|------------|---------|
|  | Forward current                      |                  | lF                   | 20         | mA      |
|  | Forward current derating (Ta ≥ 85°C  | C)               | ΔΙϝ/ΔΤα              | -0.54      | mA/°C   |
|  | Peak transient forward current       | (Note 1)         | IFP                  | 1          | ⟨A      |
| LED  | Reverse voltage                      |                  | VR                   | 5          | V       |
|  | Diode power dissipation              |                  | PD                   | 40         | mW      |
|  | Diode power dissipation derating (   | (Ta ≥ 85°C)      | ΔP <sub>D</sub> /°C  | -1.0       | mW/°C   |
|  | Junction temperature                 |                  | Tj                   | 125        | //°¢    |
|  | "H" peak output current              | (Note 2)         | Іорн                 | -0.45      | A       |
|  | "L" peak output current              | (Note 2)         | IOPL                 | 0.45       | A       |
| tor  | Output voltage                       |                  | Vo                   | 25         | V       |
| Detector                                   | Supply voltage                       |                  | Vcc                  | 25         | V       |
|  | Power dissipation                    |                  | Pc                   | 400        | mW (    |
|  | Power dissipation derating (Ta ≥25°  | C)               | ΔP <sub>C</sub> / °C | 4.0        | mW / °C |
|  | Junction temperature                 |                  | Tj                   | 125        | ) °C    |
| Oper                                       | rating frequency                     | (Note 3)         |                      | 250        | kHż     |
| Storage temperature range                  |                                      |                  | Tstg                 | -55 to 125 | CC      |
| Operating temperature range                |                                      | Topr             | -40 to 100           | , e        |         |
| Lead soldering temperature (10 s) (Note 4) |                                      | T <sub>sol</sub> | 260                  | ∕_°C       |         |
| Isola                                      | tion voltage (AC, 60 s, R.H. ≤ 60 %) | (Note 5)         | BVs                  | 5000       | Vrms    |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Note: A ceramic capacitor (0.1 µF) should be connected from pin 6 to pin 4 to stabilize the operation of the high gain linear amplifier. Failure to provide the bypassing may impair the switching property.

The total lead length between capacitor and coupler should not exceed 1 cm.

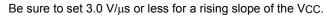
- Note 1: Pulse width  $P_W \le 1 \mu s$ , 300 pps
- Note 2: Exponential waveform pulse width  $P_W \le 2 \mu s$ ,  $f \le 15 \text{ kHz}$
- Note 3: Exponential waveform I<sub>OPH</sub> ≤-0.25 A (P<sub>W</sub> ≤80 ns), I<sub>OPL</sub> ≤+0.25 A (P<sub>W</sub> ≤80 ns), Ta = 100 °C
- Note 4: It is effective soldering area of Lead.
- Note 5: Device considered a two terminal device: pins 1, 2 and 3 shorted together, and pins 4, 5 and 6 shorted together.

## **Recommended Operating Conditions**

| Characteristics       |          | Symbol           | Min  | Тур. | Max    | Unit |
|-----------------------|----------|------------------|------|------|--------|------|
| Input current, ON     | (Note 1) | IF (ON)          | 10   | _    | 15     | mA   |
| Input voltage, OFF    |          | VF (OFF)         | 0    | _    | 0.8    | V    |
| Supply voltage        |          | Vcc              | 10   | _    | 20     | V    |
| Peak output current   |          | IOPH / IOPL      | _    | _    | ± 0.15 | Α    |
| Operating temperature |          | T <sub>opr</sub> | - 40 |      | 100    | °C   |

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

If the rising slope of the supply voltage (VCC) for the detector is steep, stable operation of the internal circuits Note: cannot be guaranteed.





## Electrical Characteristics (Ta = -40 to 100°C, unless otherwise specified)

| Characteristic                    | Characteristics                            |                  | Test<br>Circuit | Test Condition                                 |                                       | Min   | Тур.  | Max | Unit  |
|-----------------------------------|--|------------------|-----------------|--|---------------------------------------|-------|-------|-----|-------|
| Forward voltage                   | orward voltage                             |                  | _               | I <sub>F</sub> = 10 mA, Ta = 25                | s °C                                  | _     | 1.6   | 1.8 | V     |
| Temperature coefficient o voltage | Temperature coefficient of forward voltage |                  | _               | I <sub>F</sub> = 10 mA                         |                                       |       | -2.0  | _   | mV/°C |
| Input reverse current             |  | IR               | _               | V <sub>R</sub> = 5 V, Ta = 25 °C               | С                                     |       | _     | 10  | μА    |
| Input capacitance                 |  | Ст               | _               | V = 0 V, f = 1 MHz,                            | Ta = 25 °C                            | ((-)) | 45    | _   | pF    |
|                                   | "H" Level                                  | 1                | 1               | V <sub>CC</sub> = 15 V                         | V <sub>6-5</sub> = 4 V                | -0.15 | -0.35 | _   |       |
| Output current                    | n Levei                                    | IOPH             | '               | $I_F = 10 \text{ mA}$ $V_{6.5} = 10 \text{ V}$ | -0.3                                  | -0.6  | _     | _   |       |
| (Note 1)                          | "L" Level                                  | 1"1              | 2               | V <sub>CC</sub> = 15 V                         | V <sub>5-4</sub> = 2 V                | 0.15  | 0.36  | _   | Α     |
|                                   | L Levei                                    | IOPL             | 2               | $I_F = 0 \text{ mA}$                           | V <sub>5-4</sub> = 10 V               | 0.3   | 0.62  | _   |       |
| Output voltage                    | "H" Level                                  | V <sub>OH</sub>  | 3               |  | O = -100 mA,<br>F = 10 mA             | 6.0   | 8.5   | _   |       |
| Output voltage                    | "L" Level                                  | V <sub>OL</sub>  | 4               |  | o = 100 mA,<br>V <sub>F</sub> = 0.8 V |       | 0.4   | 1.0 | V     |
| Cumply ourrant                    | "H" Level                                  | Іссн             | 5               | V <sub>CC</sub> = 10 to 20 V                   | F = 10 mA 🔷                           | 5     | 2.0   | 3.0 | m ^   |
| Supply current                    | "L" Level                                  | ICCL             | 6               | V <sub>O</sub> = open                          | <sub>F</sub> = 0 mA                   | 7     | 2.0   | 3.0 | mA    |
| Threshold input current           | $L \rightarrow H$                          | I <sub>FLH</sub> | _               | V <sub>CC</sub> = 15 V, V <sub>O</sub> > 1 V   |                                       |       | 2.5   | 8   | mA    |
| Threshold input voltage           | $H \rightarrow L$                          | V <sub>FHL</sub> | _               | V <sub>CC</sub> = 15 V, V <sub>O</sub> < 1 V   |                                       | 0.8   | _     | _   | V     |
| Supply voltage                    |  | Vcc              | ((              |  | (7/4                                  | 10    | _     | 20  | V     |

Note: All typical values are at Ta = 25°C

Note: This product is more sensitive than the conventional product to static electricity (ESD) because of a lowest power consumption design.

General precaution to static electricity (ESD) is necessary for handling this component.

Note 1: Duration of IO time  $\leq$  50  $\mu$ s

## Isolation Characteristics (Ta = 25°C)

| Characteristic              | Symbol | Test Condition                     | Min              | Тур.             | Max | Unit |
|-----------------------------|--------|------------------------------------|------------------|------------------|-----|------|
| Capacitance input to output | Cs     | V = 0 V, f = 1 MHz                 | _                | 1.0              | _   | pF   |
| Isolation resistance        | Rs     | R.H. ≤ 60 %, V <sub>S</sub> = 500V | 10 <sup>12</sup> | 10 <sup>14</sup> | _   | Ω    |
| Isolation voltage           | BVs    | AC, 60 s                           | 5000             | _                | _   | Vrms |

Note: Device considered a two terminal device: pins 1, 2 and 3 shorted together, and pins 4, 5 and 6 shorted together.

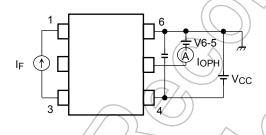
## Switching Characteristics (Ta = -40 to 100°C, unless otherwise specified)

| Characteristics                                    |                   | Symbol                              | Test<br>Circuit | Test Co   | ndition                                       | Min   | Тур.                    | Max | Unit |  |
|--|-------------------|-------------------------------------|-----------------|---|---|---|-------------------------|-----|------|--|
| Propagation delay time                             | $L \rightarrow H$ | tpLH                                |                 |   | Ta = 25 °C<br>I <sub>F</sub> = 0→10 mA        | 70  | 95                      | 170 |      |  |
|  | $H \rightarrow L$ | t <sub>pHL</sub>                    |                 |   |   | Ta = 25 °C<br>I <sub>F</sub> = 10→ 0 mA       | 70                      | 105 | 170  |  |
|  | $L \rightarrow H$ | t <sub>pLH</sub>                    |                 |   | Ta = -40 to100 °C<br>I <sub>F</sub> = 0→10 mA | 50  |                         | 200 |      |  |
| Propagation delay time                             | $H \rightarrow L$ | t <sub>pHL</sub>                    |                 |   | $V_{CC} = 20 \text{ V}$ $R_g = 30 \Omega$     | Ta = -40 to100 °C<br>I <sub>F</sub> = 10→0 mA | 50                      |     | 200  |  |
| Propagation delay skew                             | (Note 1)          | tpsk                                | 7               | $C_g = 1 \text{ nF}$<br>F = 250  kHz<br>Duty Cycle = 50 % | Ta= -40 to100 °C<br>I <sub>F</sub> = 10 mA    | -90   | _                       | 90  | ns   |  |
| Switching time dispersion between ON and OFF       |                   | t <sub>pHL</sub> -t <sub>pLH </sub> |                 |   | Ta= -40 to100 °C<br>I <sub>F</sub> = 10 mA    | -65   | /                       | 65  |      |  |
| Output rise time (10-90%)                          | 1                 | tr                                  |                 |   | I <sub>F</sub> = 0 → 10 mA                    | -√(   |                         | > — |      |  |
| Output fall time (90-10%)                          |                   | t <sub>f</sub>                      |                 |   | $I_F = 10 \rightarrow 0 \text{ mA}$           |   | 1                       | _   |      |  |
| Common mode transient i at high level output       | mmunity           | СМн                                 | 0               | V <sub>CM</sub> = 1000 Vp-p                               | IF = 10 mA<br>VO (min) = 16 V                 | -10000  | $\widehat{\mathcal{A}}$ | _   | Mus  |  |
| Common mode transient immunity at low level output |                   | CML                                 | 8               | $V_{CC} = 20 V$<br>Ta = 25 °C                             | IF = 0 mA<br>VO (max) = 1                     | 10000   | <i>9</i>                | _   | V/μs |  |

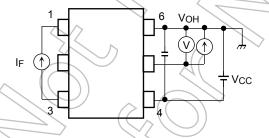
Note: All typical values are at Ta = 25 °C

Note 1: Propagation delay difference between any two parts.

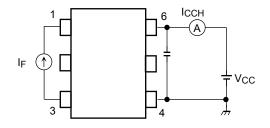




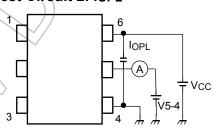
#### Test Circuit 3: Voн



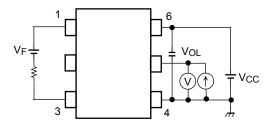
## Test Circuit 5: Icch



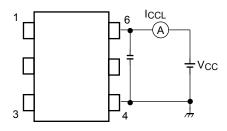
#### Test Circuit 2: IOPL



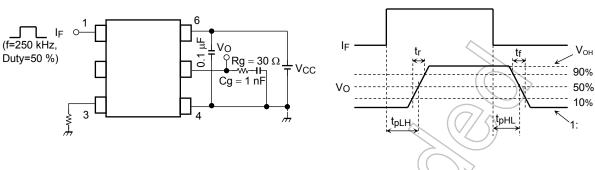
#### Test Circuit 4: Vol



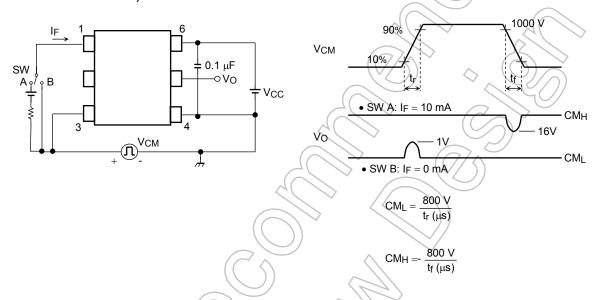
#### **Test Circuit 6: ICCL**



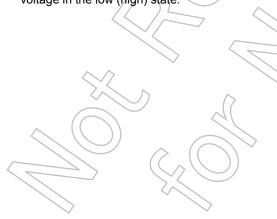
#### Test Circuit 7: tplн, tpнL, tr, tf, PWD



### Test Circuit 8: СМн, СМL



Note: CML (CMH) is the maximum rate of rise (fall) of the common mode voltage that can be sustained with the output voltage in the low (high) state.



#### RESTRICTIONS ON PRODUCT USE

Toshiba Corporation and its subsidiaries and affiliates are collectively referred to as "TOSHIBA". Hardware, software and systems described in this document are collectively referred to as "Product".

- TOSHIBA reserves the right to make changes to the information in this document and related Product without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.
- PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE
  EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH
  MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT
  ("UNINTENDED USE"). Except for specific applications as expressly stated in this document, Unintended Use includes, without
  limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, lifesaving and/or life supporting medical
  equipment, equipment used for automobiles, trains, ships and other transportation, traffic signaling equipment, equipment used to
  control combustions or explosions, safety devices, elevators and escalators, and devices related to power plant. IF YOU USE
  PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT. For details, please contact your
  TOSHIBA sales representative or contact us via our website.
- . Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any
  applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE
  FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY
  WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR
  LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND
  LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO
  SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS
  FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.
- GaAs (Gallium Arsenide) is used in Product. GaAs is harmful to humans if consumed or absorbed, whether in the form of dust or vapor. Handle with care and do not break, cut, crush, grind, dissolve chemically or otherwise expose GaAs in Product.
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without
  limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile
  technology products (mass destruction weapons). Product and related software and technology may be controlled under the
  applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the
  U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited
  except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of
  Product. Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled
  substances, including without limitation, the EU RoHS Directive. TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES
  OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.

## **TOSHIBA ELECTRONIC DEVICES & STORAGE CORPORATION**

https://toshiba.semicon-storage.com/